

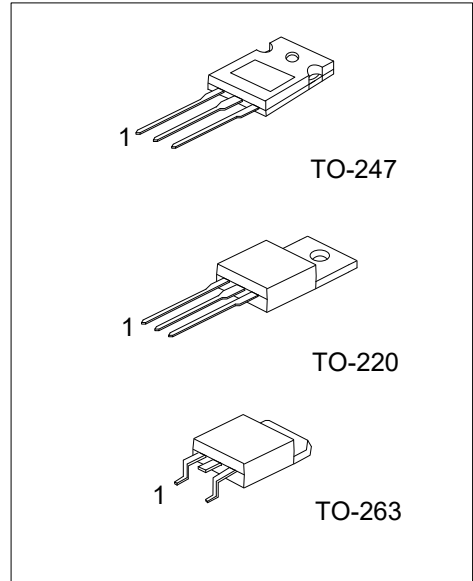


UTG10N120LNS1

Preliminary

Insulated Gate Bipolar Transistor

1200V, SMPS N-CHANNEL IGBT



■ DESCRIPTION

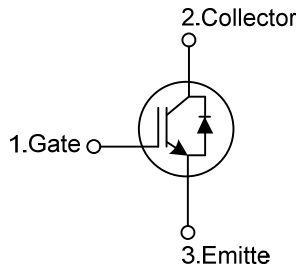
The UTC **UTG10N120LNS1** is a N-channel IGBT. it uses UTC's advanced technology to provide customers with high input impedance, high switching speed and low conduction loss, etc.

The UTC **UTG10N120LNS1** is suitable for high voltage switching, high frequency switch mode power supplies.

■ FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT),Typ.} = 1.43V @ I_C=10A, V_{GE}=15V$ ($T_C = 25^{\circ}C$)

■ SYMBOL



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTG10N120LNS1L-TA3-T	UTG10N120LNS1G-TA3-T	TO-220	G	C	E	Tube
UTG10N120LNS1L-TQ2-T	UTG10N120LNS1G-TQ2-T	TO-263	G	C	E	Tube
UTG10N120LNS1L-TQ2-R	UTG10N120LNS1G-TQ2-R	TO-263	G	C	E	Tape Reel
UTG10N120LNS1L-T47-T	UTG10N120LNS1G-T47-T	TO-247	G	C	E	Tube

Note: Pin Assignment: G: Gate C: Collector E: Emitter

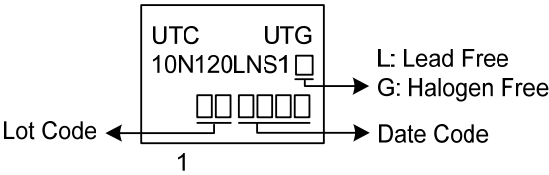
<p>UTG10N120LNS1G-TA3-T</p>	<p>(1) T: Tube, R: Tape Reel</p> <p>(2) TA3: TO-220, TQ2: TO-263, T47: TO-247</p> <p>(3) G: Halogen Free and Lead Free, L: Lead Free</p>
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■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage	V _{CES}	1200	V	
Gate-Emitter Voltage	V _{GES}	±20	V	
Transient Gate-emitter voltage (t _p < 5 ms)		±25	V	
Continuous Collector Current	I _C	T _C =25°C	20	A
		T _C =100°C	10	A
Collector Current Pulsed (Note 1)	I _{CM}	40	A	
Diode Forward Current	I _F	T _C =25°C	20	A
		T _C =100°C	10	A
Power Dissipation (T _C =25°C)	P _D	TO-220	96	W
		TO-263	245	W
		TO-247		
Operating Junction Temperature	T _J	-40 ~ +150	°C	
Storage Temperature Range	T _{STG}	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Absolute maximum ratings are those values beyond which the device could be permanently damaged.

2. Pulse width limited by maximum junction temperature.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT	
Junction to Case	θ _{JC}	TO-220	1.3	°C/W
		TO-263		
		TO-247	0.51	°C/W

■ ELECTRICAL CHARACTERISTICS (T_c=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Collector-Emitter Breakdown Voltage	BV _{CES}		1200			V	
Collector Cut-Off Current	I _{CES}	V _{CE} =1200V, V _{GE} =0V			5	μA	
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			±250	nA	
ON CHARACTERISTICS							
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}	4.0		7.6	V	
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =10A, V _{GE} =15V	T _C =25°C	1.43	2.1	V	
			T _C =125°C	2.2		V	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{IES}	V _{CE} =25V, V _{GE} =0V, f=1MHz		1930		pF	
Output Capacitance	C _{OES}			55.5		pF	
Reverse Transfer Capacitance	C _{RES}			36.2		pF	
SWITCHING CHARACTERISTICS							
Total Gate Charge	Q _G	V _{CE} =600V, I _C =10A, V _{GE} =15V		105.3		nC	
Gate-Emitter Charge	Q _{GE}			21.8		nC	
Gate-Collector Charge	Q _{GC}			46		nC	
Turn-On Delay Time	t _{DON}	V _{CC} =600V, I _C =10A, R _G =5Ω, V _{GE} =0~15V, L=500μH		9.9		ns	
Rise Time	t _R			15.7		ns	
Turn-Off Delay Time	t _{DOFF}			104.9		ns	
Fall Time	t _F			256.2		ns	
Turn-On Switching Loss	E _{ON}				0.56		mJ
Turn-Off Switching Loss	E _{OFF}				0.89		mJ
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Forward Voltage Drop	V _F		I _F =10A			2.5	V
Reverse Recovery Time	t _{rr}	I _F =10A, dI/dt=100A/μS, V _{CC} =400V		49.2		ns	
Reverse Recovery Charge	Q _{rr}				0.56		μC

■ TEST CIRCUIT AND WAVEFORMS

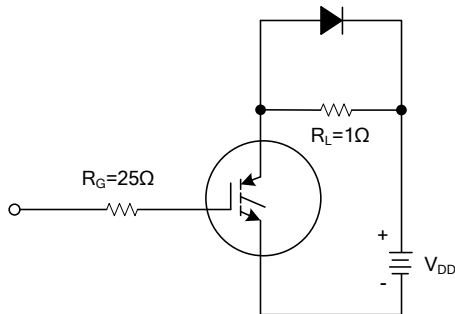


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

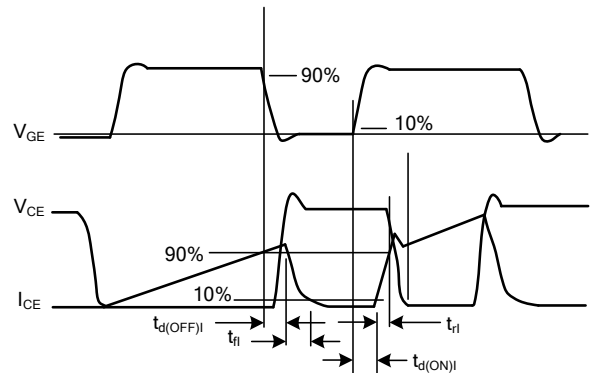


Fig 2. SWITCHING TEST WAVEFORMS

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